Power Inductor

UHP252010NF-SERIES

1. Features

- 1. This specification applies Low Profile Power Inductors.
- 2. 100% Lead(Pb) & Halogen-Free and RoHS compliant.

2. Dimension



Series	A(mm)	B(mm)	C(mm)	D(mm)	E(mm)
UHP252010NF	2.5 -0.1/+0.2	2.0 -0.1/+0.2	1.0max.	0.85 ref.	0.80 ref.

Units: mm

3. Part Numbering

UHP	25201 0) NF	-	4R7	Μ
А	В	С		D	Е
A: Series					
B: Dimension					
C: Lead Free		Mate	erial		
D: Inductance		4R7=	4.7u⊦	1	
E: Inductance T	olerance	M=±2	20%		
- ···	-				

4. Specification

TAI-TECH Part Number	Inductance (uH)	Tolerance (%)	Test Frequency (Hz)	DCR (Ω) ±20%	l sat (A) typ.	l sat (A) Max.	l rms (A) typ	l rms (A) Max.
UHP252010NF-R47M	0.47	±20%	0.1V/1M	0.030	2.85	2.57	2.80	2.50
UHP252010NF-R68 M	0.68	±20%	0.1V/1M	0.039	2.70	2.45	2.45	2.20
UHP252010NF-1R0 M	1.0	±20%	0.1V/1M	0.055	2.45	2.05	2.20	1.80
UHP252010NF-1R5 M	1.5	±20%	0.1V/1M	0.090	1.80	1.70	1.70	1.55
UHP252010NF-2R2M	2.2	±20%	0.1V/1M	0.114	1.60	1.55	1.55	1.40
UHP252010NF-3R3M	3.3	±20%	0.1V/1M	0.170	1.30	1.10	1.25	1.10
UHP252010NF-4R7M	4.7	±20%	0.1V/1M	0.250	1.10	0.95	1.05	0.92
UHP252010NF-6R8M	6.8	±20%	0.1V/1M	0.370	0.95	0.80	0.85	0.76
UHP252010NF-100M	10	±20%	0.1V/1M	0.470	0.75	0.65	0.75	0.67
UHP252010NF-150M	15	±20%	0.1V/1M	0.750	0.55	0.45	0.55	0.50
UHP252010NF-220M	22	±20%	0.1V/1M	1.120	0.50	0.40	0.50	0.45

Note:

Isat : Based on inductance change $~~(\ \bigtriangleup L/L0$: $\leq -30\%\,)$ @ ambient temp. 25 $^\circ\!\!\mathbb{C}$

Irms : Based on temperature rise $(\triangle T : 40^{\circ} C.)$ Max







No.	Description	Specification
a.	Core	Ferrite Core
b.	Coating	Epoxy with magnetic powder
С	Termination	Tin Pb Free
d	Wire	Enameled Copper Wire





Exposed wire tolerance limit of coating resin part on product side. Size of exposed wire occurring to coating resin is specified below. 1. Width direction (dimension a): Acceptable when $a \le w/2$

Nonconforming when a > w/2

- 2. Length direction (dimension b): Dimension b is not specified.
- 3. The total area of exposed wire occurring to each sides is not greater than 50% of coating resin area, and is acceptable.

TAI-TECH

6. Reliability and Test Condition

Item	Performance	Test Condition			
Operating Temperature	-55~+125 $^\circ\!\mathbb{C}$ (For products in unopened tape package, less than 40 $^\circ\!\mathbb{C}$)				
Electrical Performance	Test				
Inductance L		Agilent-4291, Agilent-4287			
Q	-	Agilent-4192, Agilent-4285			
SRF	Refer to standard electrical characteristic list	Agilent-4291			
	-	-			
DC Resistance		Agilent-4338			
Rated Current	Base on temp. rise & △L/L0A≦30%.	Saturation DC Current (Isat) will cause L0 to drop approximately \triangle L(%).			
Temperature Rise Test	ΔT 40°C Max	 Heat Rated Current (Irms) will cause the coil temperature approximately △T(℃) without core loss. 1.Applied the allowed DC current. 2.Temperature measured by digital surface thermometer 			
Mechanical Performanc	e Test				
	Appearance : No damage.				
Solder Heat Resistance	Inductance : within±10% of initial value Q : Shall not exceed the specification value.	Temperature (°C) Time Temperature (s) Temperature ramp/immersion rate Number of heat cycles			
	RDC: within ±15% of initial value and shall not exceed the specification value	260 ±5 (solder temp) 10 ±1 25mm/s±6 mm/s 1			
		Depth: completely cover the termination			
Solderability Test	More than 95% of terminal electrode should be covered with solder.	Preheat: 150°C,60sec. Solder: Sn99.5%-Cu0. 5% Temperature: 245±5°C Flux for lead free: Rosin. 9.5% Dip time: 4±1sec Depth: completely cover the termination			
Reliability Test					
Life Test		Preconditioning:Run through IR reflow for 2 times.(IPC/JEDEC J_STD-020DClassification Reflow Profiles Temperature : 125±2°C (Bead) Temperature : 85±2°C (Inductor) Applied current : rated current Duration : 1000±12hrs Measured at room temperature after placing for 24±2 hrs			
Thermal shock	Appearance : No damage. Inductance : within±10% of initial value Q : Shall not exceed the specification value. RDC : within±15% of initial value and shall not exceed the specification value	Preconditioning:Run through IR reflow for 2 times.(IPC/JEDEC J-STD-020DClassification Reflow Profiles Step1 : -40±2°C 30±5min Step2 : 25±2°C ≤0.5min Step3 : 105±2°C 30±5min Number of cycles : 500 Measured at room fempraturc after placing for 24±2 hrs			
Humidity Resistance Test		Preconditioning:Run through IR reflow for 2 times.(IPC/JEDEC J-STD-020DClassification Reflow Profiles Humidity : 85±2% R.H, Temperature : 85°C±2°C Duration : 1000hrs Min. with 100% rated current Measured at room temperature after placing for 24±2 hrs			
Vibration Test		Preconditioning:Run through IR reflow for 2 times.(IPC/JEDEC J_STD-020DClassification Reflow Profiles Oscillation Frequency: 10~2K~10Hz for 20 minutes Equipment : Vibration checker Total Amplitude:1.52mm±10% Testing Time : 12 hours(20 minutes, 12 cycles each c orientations) ∘			

7. Soldering and Mounting

7-1. Soldering

Mildly activated rosin fluxes are preferred. TAI-TECH terminations are suitable for all wave and re-flow soldering systems. If hand soldering cannot be avoided, the preferred technique is the utilization of hot air soldering tools.

7-1.1 Solder re-flow:

Recommended temperature profiles for re-flow soldering in Figure 1.

7-1.2 Soldering Iron(Figure 2):

Products attachment with a soldering iron is discouraged due to the inherent process control limitations. In the event that a soldering iron must be employed the following precautions are recommended.

- Preheat circuit and products to 150 $^\circ\!\mathrm{C}$ · Never contact the ceramic with the iron tip • 355℃ tip temperature (max)

• 1.0mm tip diameter (max)

· Use a 20 watt soldering iron with tip diameter of 1.0mm · Limit soldering time to 4~5 sec.



7-2. Recommended PC Board Pattern



L(mm)	G(mm)	H(mm)
2.6	0.8	2.1

8. Packaging Information

8-1. Reel Dimension



8-2. Tape Dimension / 8mm

Туре	A(mm)	B(mm)	C(mm)	D(mm)
7"x8mm	8.4±1.0	50 min.	13±0.8	178±2



Series	Size	Bo(mm)	Ao(mm)	Ko(mm)	P(mm)	t(mm)
UHP	252010	2.85±0.1	2.45±0.1	1.40±0.1	4.0±0.1	0.23±0.05

8-3. Packaging Quantity

Chip size	252010
Chip / Reel	2000

8-4. Tearing Off Force



The force for tearing off cover tape is 15 to 80 grams in the arrow direction under the following conditions.

Room Temp.	Room Humidity	Room atm	Tearing Speed
(°C)	(%)	(hPa)	mm/min
5~35	45~85	860~1060	300

Application Notice

- Storage Conditions
 - To maintain the solderability of terminal electrodes:
 - 1. TAI-TECH products meet IPC/JEDEC J-STD-020D standard-MSL, level 1.
 - 2. Temperature and humidity conditions: Less than 40 $^\circ\!\mathrm{C}$ $\,$ and 60% RH.
 - 3. Recommended products should be used within 12 months form the time of delivery.
 - 4. The packaging material should be kept where no chlorine or sulfur exists in the air.

Transportation

- 1. Products should be handled with care to avoid damage or contamination from perspiration and skin oils.
- 2. The use of tweezers or vacuum pick up is strongly recommended for individual components.
- 3. Bulk handling should ensure that abrasion and mechanical shock are minimized.





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以下測試樣品係由申請廠商所提供及確認 (The following sample(s) was/were submitted and identified by/on behalf of the applicant as):

=======================================	===	
測試期間(Testing Period)	:	2013/12/30 TO 2014/01/07
收件日期(Sample Receiving Date)	:	2013/12/30
樣品型號(Style/Item No.)	:	HPC, MDC, FPC, FWP, SPC, SPI, UHP, DFP, TLPC, TLPH, TLI SERIES
樣品名稱(Sample Description)	:	SMD POWER INDUCTOR

測試結果(Test Results) : 請見下一頁 (Please refer to next pages).



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<u>測試結果(Test Results)</u>

測試部位(PART NAME)No.1 : 整體混測(MIXED ALL PARTS)

測試項目 (Test Items)	單位 (Unit)	測試方法 (Method)	方法偵測 極限値 (MDL)	結果 (Result) No.1
鎘 / Cadmium (Cd)	mg/kg	參考IEC 62321-5: 2013方法, 以感應耦合 電漿原子發射光譜儀檢測. / With reference to IEC 62321-5: 2013 and performed by ICP-AES.	2	n.d.
鉛 / Lead (Pb)	mg/kg	參考IEC 62321-5: 2013方法, 以感應耦合 電漿原子發射光譜儀檢測. / With reference to IEC 62321-5: 2013 and performed by ICP-AES.	2	n.d.
汞 / Mercury (Hg)	mg/kg	參考IEC 62321-4: 2013方法, 以感應耦合 電漿原子發射光譜儀檢測. / With reference to IEC 62321-4: 2013 and performed by ICP-AES.	2	n.d.
六價鉻 / Hexavalent Chromium Cr(VI)	mg/kg	參考IEC 62321: 2008方法,以UV-VIS檢測. / With reference to IEC 62321: 2008 and performed by UV-VIS.	2	n.d.

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測試項目 (Test Items)	單位 (Unit)	測試方法 (Method)	方法偵測 極限値 (MDL)	結果 (Result) No.1
鄰苯二甲酸甲苯基丁酯 / BBP (Benzyl butyl phthalate) (CAS No.: 85-68-7)	%	參考EN 14372, 以氣相層析/質譜儀檢測之. / With reference to EN 14372. Analysis was performed by GC/MS.	0.003	n.d.
鄰苯二甲酸二 (2-乙基己基)酯 / DEHP (Di- (2-ethylhexyl) phthalate) (CAS No.: 117-81-7)	%	參考EN 14372, 以氣相層析/質譜儀檢測之. / With reference to EN 14372. Analysis was performed by GC/MS.	0.003	n.d.
鄰苯二甲酸二異癸酯 / DIDP (Di- isodecyl phthalate) (CAS No.: 26761-40-0; 68515-49-1)	%	參考EN 14372, 以氣相層析/質譜儀檢測之. / With reference to EN 14372. Analysis was performed by GC/MS.	0.01	n.d.
鄰苯二甲酸二異壬酯 / DINP (Di- isononyl phthalate) (CAS No.: 28553-12-0; 68515-48-0)	. %	參考EN 14372, 以氣相層析/質譜儀檢測之. / With reference to EN 14372. Analysis was performed by GC/MS.	0.01	n.d.
鄰苯二甲酸二正辛酯 / DNOP (Di-n- octyl phthalate) (CAS No.: 117- 84-0)	%	參考EN 14372, 以氣相層析/質譜儀檢測之. / With reference to EN 14372. Analysis was performed by GC/MS.	0.003	n.d.
鄰苯二甲酸二丁酯 / DBP (Dibutyl phthalate) (CAS No.: 84-74-2)	%	參考EN 14372, 以氣相層析/質譜儀檢測之. / With reference to EN 14372. Analysis was performed by GC/MS.	0.003	n.d.
鄰苯二甲酸二異丁酯 / DIBP (Di- isobutyl phthalate) (CAS No.: 84- 69-5)	%	參考EN 14372, 以氣相層析/質譜儀檢測之. / With reference to EN 14372. Analysis was performed by GC/MS.	0.003	n.d.

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測試項目 (Test Items) 六溴環十二烷及所有主要被辨别出的 異構物 / Hexabromocyclododecane (HBCDD) and all major diastereoisomers identified (α - HBCDD, β - HBCDD, γ - HBCDD) (CAS No.: 25637-99-4 and 3194-55-6 (134237-51-7, 134237-50-6, 134237-52-8))		測試方法 (Method) 參考IEC 62321: 2008方法,以氣相層析/質 譜儀檢測. / With reference to IEC 62321: 2008 method. Analysis was performed by GC/MS.	方法偵測 極限値 (MDL) 5	結果 (Result) No.1 n.d.
多溴聯苯總和 / Sum of PBBs	mg/kg	參考IEC 62321: 2008方法,以氣相層析/質 譜儀檢測. / With reference to IEC 62321: 2008 and performed by GC/MS.	-	n.d.
一溴聯苯 / Monobromobiphenyl	mg/kg		5	n.d.
二溴聯苯 / Dibromobiphenyl	mg/kg		5	n.d.
三溴聯苯 / Tribromobiphenyl	mg/kg		5	n.d.
四溴聯苯 / Tetrabromobiphenyl	mg/kg		5	n.d.
五溴聯苯 / Pentabromobiphenyl	mg/kg		5	n.d.
六溴聯苯 / Hexabromobiphenyl	mg/kg		5	n.d.
七溴聯苯 / Heptabromobiphenyl	mg/kg		5	n.d.
八溴聯苯 / Octabromobiphenyl	mg/kg		5	n.d.
九溴聯苯 / Nonabromobiphenyl	mg/kg		5	n.d.
十溴聯苯 / Decabromobiphenyl	mg/kg		5	n.d.

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測試項目 (Test Items)	單位 (Unit)	測試方法 (Method)	方法偵測 極限値 (MDL)	結果 (Result) No.1
多溴聯苯醚總和 / Sum of PBDEs	mg/kg		-	n.d.
一溴聯苯醚 / Monobromodiphenyl ether	mg/kg		5	n.d.
二溴聯苯醚 / Dibromodiphenyl ether	mg/kg		5	n.d.
三溴聯苯醚 / Tribromodiphenyl ether	mg/kg		5	n.d.
四溴聯苯醚 / Tetrabromodiphenyl ether	mg/kg	參考IEC 62321: 2008方法,以氣相層析/質 譜儀檢測. / With reference to IEC 62321: 2008 and performed by GC/MS.	5	n.d.
五溴聯苯醚 / Pentabromodiphenyl ether	mg/kg		5	n.d.
六溴聯苯醚 / Hexabromodiphenyl ether	mg/kg		5	n.d.
七溴聯苯醚 / Heptabromodiphenyl ether	mg/kg		5	n.d.
八溴聯苯醚 / Octabromodiphenyl ether	mg/kg		5	n.d.
九溴聯苯醚 / Nonabromodiphenyl ether	mg/kg		5	n.d.
十溴聯苯醚 / Decabromodiphenyl ether	mg/kg		5	n.d.
鹵素 / Halogen				
鹵素(氟)/ Halogen-Fluorine(F) (CAS No.: 14762-94-8)	mg/kg	參考BS EN 14582:2007, 以離子層析儀分 析. / With reference to BS EN 14582:2007. Analysis was performed by IC.	50	n.d.
鹵素(氯)/ Halogen-Chlorine (Cl) (CAS No.: 22537-15-1)	mg/kg		50	n.d.
鹵素(溴)/ Halogen-Bromine (Br) (CAS No.: 10097-32-2)	mg/kg		50	n.d.
鹵素(碘)/ Halogen-Iodine (I) (CAS No.: 14362-44-8)	mg/kg		50	n.d.

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Test Report

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備註(Note):

- 1. mg/kg = ppm; 0.1wt% = 1000ppm
- 2. n.d. = Not Detected (未檢出)
- 3. MDL = Method Detection Limit (方法偵測極限值)
- 4. "-" = Not Regulated (無規格値)
- 5. 樣品的測試是基於申請人要求混合測試,報告中的混合測試結果不代表其中個別單一材質的含量. (The samples was/were analyzed on behalf of the applicant as mixing sample in one testing. The above results was/were only given as the informality value.)

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1) 根據以下的流程圖之條件,樣品已完全溶解。(六價 路測試方法除外) / These samples were discoluded totally by any conditioning method according to below flow that (0.5) be to any the discoluted totally by any conditioning method according to below flow that (0.5)

- dissolved totally by pre-conditioning method according to below flow chart. (Cr⁶⁺ test method excluded)
- 测试人员:楊登律 / Name of the person who made measurement: Climbgreat Yang
 测试負責人:張啓興 / Name of the person in charge of measurement: Troy Chang



Note** (For IEC 62321)

(1) 針對非金屬材料加入鹼性消化液,加熱至 90~95℃萃取. / For non-metallic material, add alkaline digestion reagent and heat to 90~95℃.
 (2) 針對金屬材料加入純水,加熱至沸腾萃取. / For metallic material, add pure water and heat to boiling.

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多溴聯苯/多溴聯苯醚分析流程圖 / PBB/PBDE analytical FLOW CHART

■ 測試人員:翁賜彬 / Name of the person who made measurement: Roman Wong

■ 測試負責人:張啓興 / Name of the person in charge of measurement: Troy Chang

初次測試程序 / First testing process -------

選擇性篩檢程序 / Optional screen process ========

確認程序 / Confirmation process - · - · ▶



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六溴環十二烷分析流程圖 / HBCDD analytical flow chart

- 測試人員:翁賜彬 / Name of the person who made measurement: Roman Wong
- 測試負責人:張啓興 / Name of the person in charge of measurement: Troy Chang



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可塑劑分析流程圖 / Analytical flow chart of phthalate content

- 測試人員:翁賜彬 / Name of the person who made measurement: Roman Wong
- 測試負責人:張啓興 / Name of the person in charge of measurement: Troy Chang



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鹵素分析流程圖 / Analytical flow chart of halogen content

- 測試人員:陳恩臻 / Name of the person who made measurement: Rita Chen
- 測試負責人:張啓興 / Name of the person in charge of measurement: Troy Chang



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* 照片中如有箭頭標示,則表示為實際檢測之樣品/部位. *

(The tested sample / part is marked by an arrow if it's shown on the photo.)



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